BYW29EX series

GENERAL DESCRIPTION

Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

PINNING - SOD113

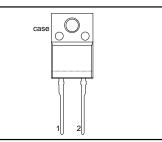
QUICK REFERENCE DATA

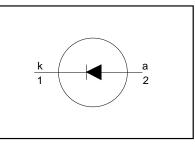
SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{RRM} V _F I _{F(AV)} t _{rr} I _{RRM}	BYW29EX- Repetitive peak reverse voltage Forward voltage Forward current Reverse recovery time Repetitive peak reverse current	150 150 0.895 8 25 0.2	200 200 0.895 8 25 0.2	V V A ns A

PIN CONFIGURATION

SYMBOL

PIN	DESCRIPTION	
1	cathode	
2	anode	
case	isolated	





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	AX.	UNIT
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		- -	-150 150 150 150	-200 200 200 200	V V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; T _{hs} ≤ 106 °C sinusoidal; a = 1.57;	-		3	A
I _{F(RMS)} I _{FRM}	RMS forward current Repetitive peak forward current	$T_{hs} \le 109 \ ^{\circ}C$ t = 25 µs; δ = 0.5; $T_{hs} \le 106 \ ^{\circ}C$		11	.3 .3 6	A A A
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		0 8	A A
l ² t I _{RRM} I _{RSM}	Non-repetitive peak reverse	$ \begin{array}{l} V_{\text{RVM}(\text{max})} \\ t = 10 \text{ ms} \\ t_{\text{p}} = 2 \ \mu \text{s}; \ \delta = 0.001 \\ t_{\text{p}} = 100 \ \mu \text{s} \end{array} $		0	2 .2 .2	A ² s A A
T _{stg} T _j	current Storage temperature Operating junction temperature		-40 -		50 50	°C °C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	ARAMETER CONDITIONS		MIN.	MAX.	UNIT
V _c	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k Ω	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65% ; clean and dustfree	-		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	рF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs} R _{th j-a}	heatsink	with heatsink compound without heatsink compound in free air	-	- - 55	5.5 7.2 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

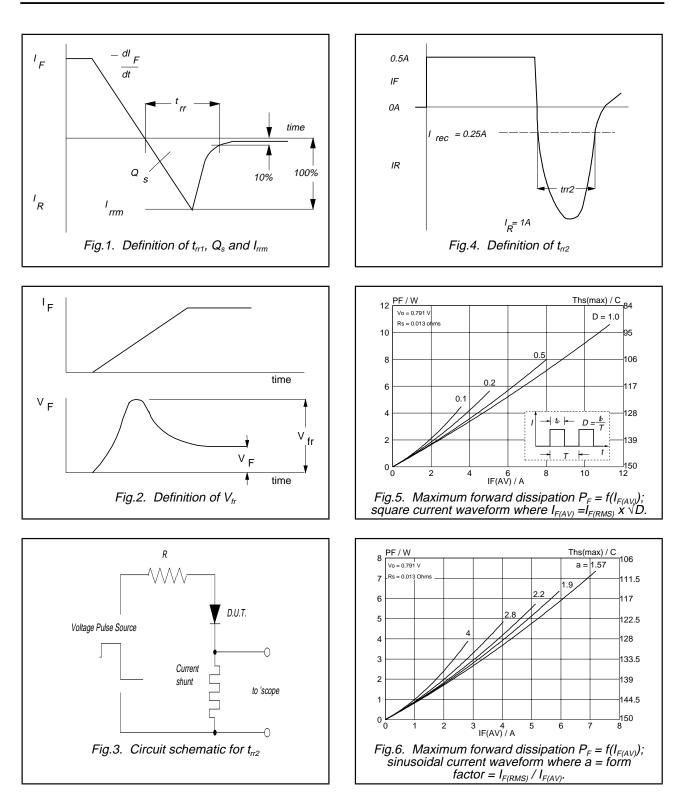
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	I _F = 8 A; T _j = 150°C I _F = 8 A	-	0.80 0.92	0.895 1.05	V V
I _R	Reverse current	$ I_F = 20 A V_R = V_{RVM}; T_j = 100 °C V_R = V_{RVM} $		1.1 0.2 2	1.3 0.6 10	V mA μA

DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

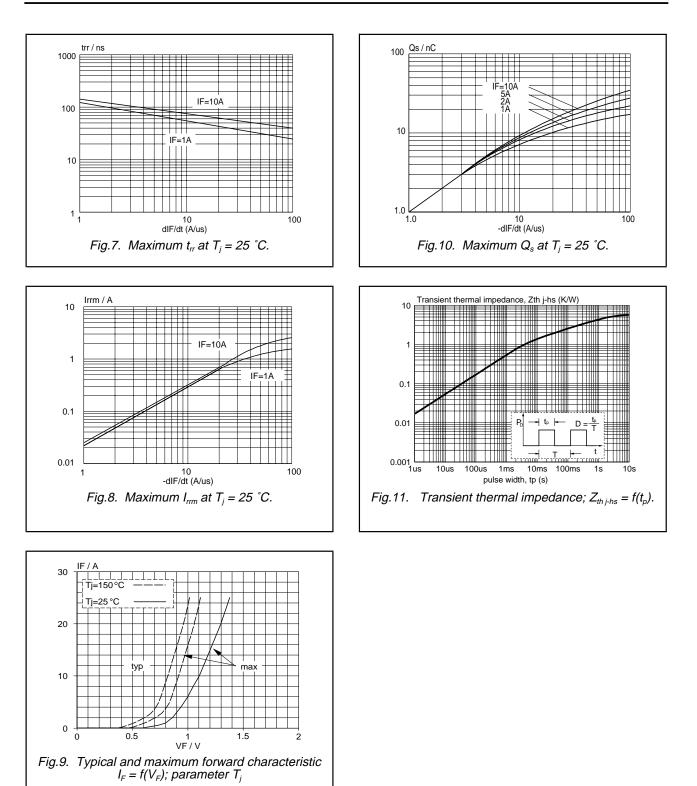
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q _s	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu \text{s}$	-	4	11	nC
t _{rr1}	Reverse recovery time	I _F = 1 A; V _R ≥ 30 V; -dI _F /dt = 100 A/μs	-	20	25	ns
	Reverse recovery time Forward recovery voltage	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$ $I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A}/\mu\text{s}$	-	15 1	20	ns V





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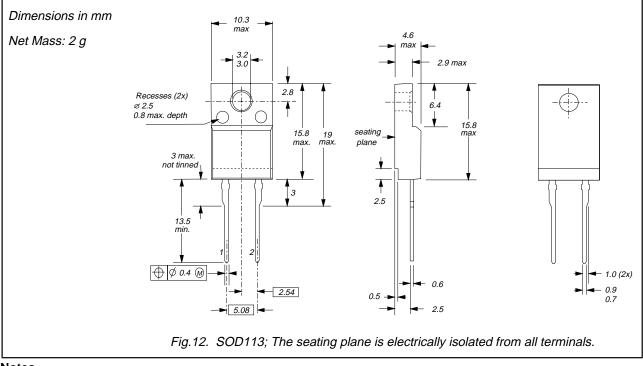
Rectifier diodes ultrafast, rugged



Downloaded from Elcodis.com electronic components distributor

BYW29EX series

MECHANICAL DATA



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

BYW29EX series

DEFINITIONS

Data sheet status				
Objective specification	Objective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at this specification is not in	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.			
Application information				
Where application inform	ation is given, it is advisory and does not form part of the specification.			
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